



20V N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C
20V	$56m\Omega @ V_{GS} = 4.5V$	2.9A
	$65m\Omega @ V_{GS} = 2.5V$	2.7A
	93mΩ @ V _{GS} = 1.8V	2.2A
	140mΩ @ V _{GS} = 1.5V	1.8A

Description and Applications

This MOSFET has been designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- General Purpose Interfacing Switch
- Power Management Functions
- DC-DC Converters
- Analog Switch

Features and Benefits

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

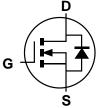
Mechanical Data

- Case: SOT323
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (a)
- Weight: 0.027 grams (Approximate)

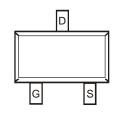




Top View



Equivalent Circuit



Top View

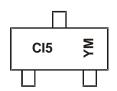
Ordering Information (Note 4)

Part Number	Case	Packaging
DMN2053UW-7	SOT323	3,000/Tape & Reel
DMN2053UW-13	SOT323	10.000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



CI5 = Product Type Marking Code YM = Date Code Marking \overline{Y} = Year (ex: G = 2019) M = Month (ex: 9 = September)

Date Code Key

Year	2018	2	019	2020	2	2021	2022		2023	2024		2025
Code	F		G	Н			J		K	L		M
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	V_{DSS}	20	V
Gate-Source Voltage	V_{GSS}	±12	V
Continuous Drain Current (Note 6) V _{GS} = 4.5V	Ι _D	2.9 2.3	А
Pulsed Drain Current (10µs Pulse, Duty Cycle=1%)	I _{DM}	20	Α
Maximum Body Diode Forward Current (Note 5)	Is	1.0	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		P_{D}	0.47	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{ heta JA}$	268	°C/W
Total Power Dissipation (Note 6)		P_D	0.7	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{ heta JA}$	178	°C/W
Operating and Storage Temperature Range		$T_{J_i}T_{STG}$	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV _{DSS}	20	_	_	V	$V_{GS} = 0V$, $I_D = 1mA$
Zero Gate Voltage Drain Current @T _C = +25°C	IDSS	_	_	1	μΑ	$V_{DS} = 20V$, $V_{GS} = 0V$
Gate-Source Leakage	I _{GSS}	_	_	±1	μΑ	$V_{GS} = \pm 10V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V _{GS(TH)}	0.35	_	1.0	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$
			39	56		$V_{GS} = 4.5V, I_D = 2A$
Static Drain-Source On-Resistance	D- avan		45	65	mΩ	$V_{GS} = 2.5V, I_D = 2A$
Static Drain-Source On-Nesistance	R _{DS(ON)}		51	93	11122	$V_{GS} = 1.8V, I_D = 1A$
		_	75	140		$V_{GS} = 1.5V, I_D = 0.5A$
Diode Forward Voltage	V_{SD}	_	0.7	1.0	V	$V_{GS} = 0V, I_{S} = 1A$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	C _{iss}	_	369	_	pF	101/11/101/
Output Capacitance	Coss		54	_	pF	$V_{DS} = 10V, V_{GS} = 0V,$ - f = 1.0MHz
Reverse Transfer Capacitance	C _{rss}		32	_	pF	1 – 1.001112
Gate Resistance	R_g	_	4.1	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$
Total Gate Charge	Q_g	_	3.6	_	nC	
Gate-Source Charge	Q _{gs}	_	0.4	_	nC	$V_{GS} = 4.5V, V_{DS} = 10V, I_D = 6A$
Gate-Drain Charge	Q_{gd}	_	1.0	_	nC	
Turn-On Delay Time	t _{D(ON)}	_	2.6	_	ns	
Turn-On Rise Time	t _R	_	3.0	_	ns	$V_{DD} = 10V, V_{GS} = 5V,$
Turn-Off Delay Time	t _{D(OFF)}	_	12.5	_	ns	$R_G = 6\Omega$, $I_D = 6A$
Turn-Off Fall Time	t _F	_	3.6	_	ns	
Reverse Recovery Time	t _{RR}	_	6.0	_	ns	I _F = 1.0A, di/dt = 100A/μs
Reverse Recovery Charge	Q _{RR}	_	0.9	_	nC	$I_F = 1.0A$, $di/dt = 100A/\mu s$

Notes:

^{5.} Device mounted on FR-4 substrate PC board, with minimum recommended pad layout.6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.

^{7.} Short duration pulse test used to minimize self-heating effect.

^{8.} Guaranteed by design. Not subject to product testing.



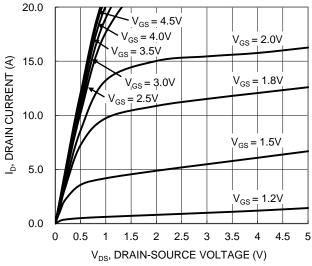


Figure 1. Typical Output Characteristic

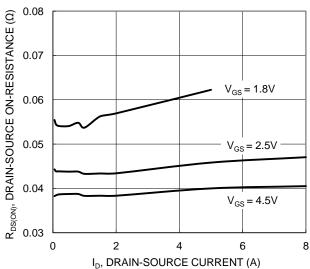


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

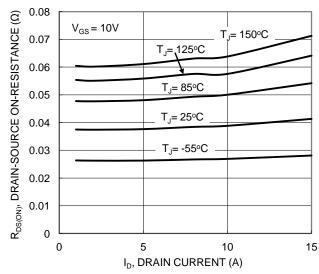


Figure 5. Typical On-Resistance vs. Drain Current and Temperature

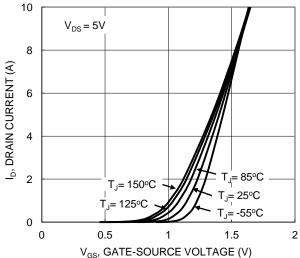


Figure 2. Typical Transfer Characteristic

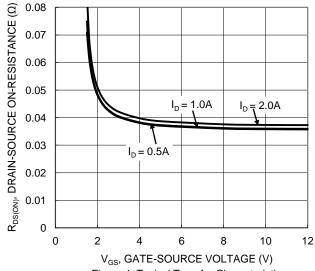


Figure 4. Typical Transfer Characteristic

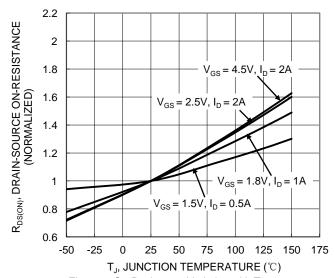


Figure 6. On-Resistance Variation with Temperature



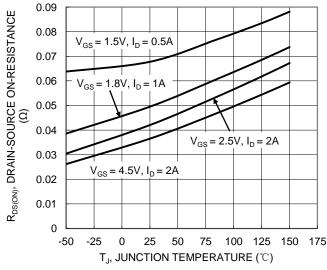
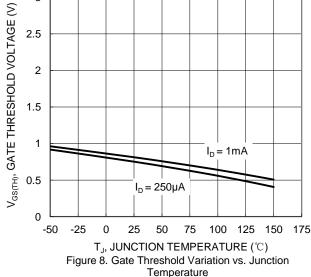


Figure 7. On-Resistance Variation with Temperature



3

Temperature

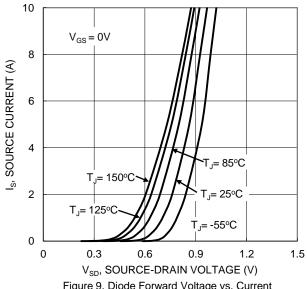
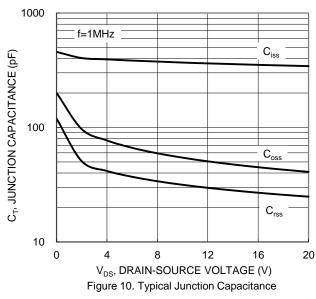
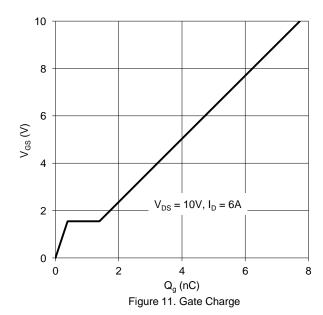


Figure 9. Diode Forward Voltage vs. Current



100 R_{DS(ON)} Limited $P_W = 100 \mu s$ 10 ID, DRAIN CURRENT (A) 1 0.1 $T_{J(Max)} = 150$ °C $T_C = 25^{\circ}C$ 0.01 ₩ DC Single Pulse DUT on 1*MRP board $V_{GS} = 4.5V$ 0.001 0.1 10 V_{DS}, DRAIN-SOURCE VOLTAGE (V) Figure 12. SOA, Safe Operation Area



100



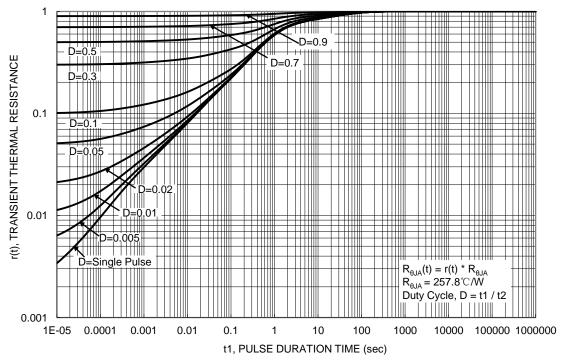


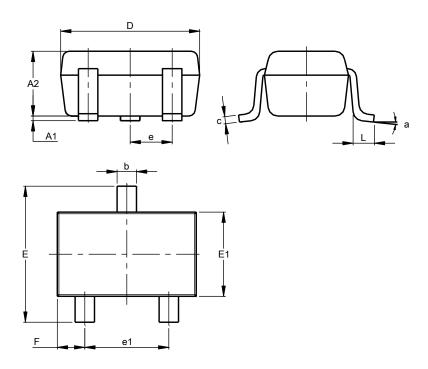
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

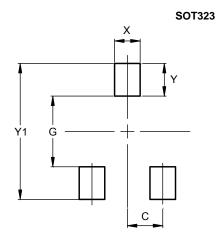
SOT323



SOT323							
Dim	Min	Max	Тур				
A1	0.00	0.10	0.05				
A2	0.90	1.00	0.95				
b	0.25	0.40	0.30				
С	0.10	0.18	0.11				
D	1.80	2.20	2.15				
Е	2.00	2.20	2.10				
E1	1.15	1.35	1.30				
е	C).650 B	SC				
e1	1.20	1.40	1.30				
F	0.375	0.475	0.425				
L	0.25	0.40	0.30				
а	0°	8°					
All	All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)				
С	0.650				
G	1.300				
Х	0.470				
Y	0.600				
Y1	2 500				

July 2019



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